

**DESCRIPTION**

The **SD 100-42-21-231** is a red enhanced detector/amplifier that combines a silicon photodiode with an opamp without a feedback network, Packaged in a hermetic TO-5 metal can package.

**FEATURES**

- Low Noise
- Red Enhanced
- Custom Feedback
- High Speed

**RELIABILITY**

Contact Luna for recommendations on specific test conditions and procedures.

**APPLICATIONS**

- Instrumentation
- Industrial
- Medical



**ABSOLUTE MAXIMUM RATINGS**

T<sub>a</sub> = 23°C UNLESS OTHERWISE NOTED

SYMBOL	MIN	TYPE	MAX	UNITS
Voltage Supplies	±5	±15	±18	V
Input Offset Voltage	-	1	2	mV
Input Voltage Noise @ f=10KHz	-	12	-	nV/√Hz
Input Bias Current	-	15	40	pA
Input Current Noise @ f=10KHz	-	20	30	fA/√Hz
Gain Bandwidth Product	-	18	-	MHz
Supply Current	-	6.5	7	mA
Storage Temperature	-65	-	+125	°C
Operating Temperature	-40	-	-85	°C

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

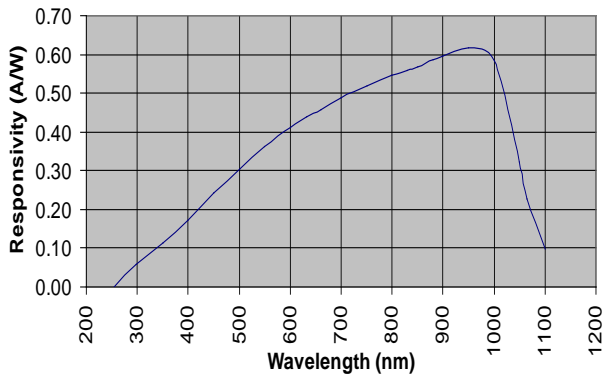
T<sub>a</sub> = 23°C UNLESS NOTED OTHERWISE

**OPTO-ELECTRICAL PARAMETERS**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Dark Current	V <sub>R</sub> = 10 V	-	-	10	nA
Shunt Resistance	V <sub>R</sub> = 0 mV	300	-	-	MΩ
Junction Capacitance	V <sub>R</sub> = 0V; f = 1 MHz	-	87	-	pF
	V <sub>R</sub> = 10V; f = 1 MHz	-	18	-	
Spectral Application Range	Spot Scan	250	-	1100	nm
Responsivity	λ = 450nm, V <sub>R</sub> = 0 V	-	.20	-	A/W

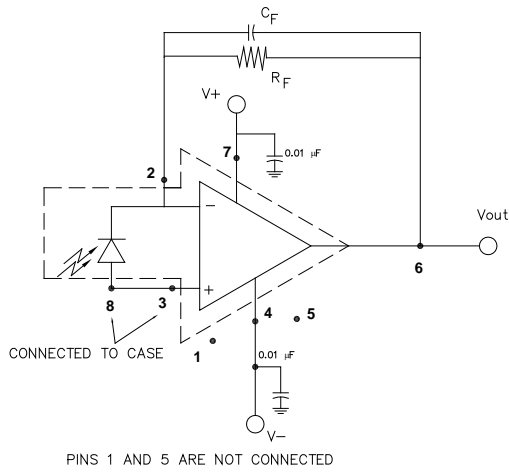
**TYPICAL PERFORMANCE**

**SPECTRAL RESPONSE**

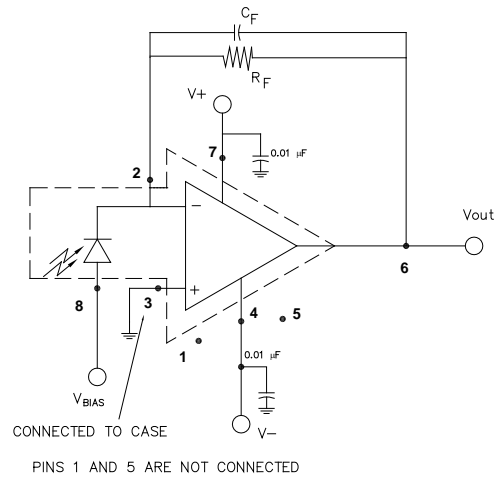


**SCHEMATIC AND CONNECTION DIAGRAM**

PHOTOVOLTAIC MODE



PHOTOCONDUCTIVE MODE



**Note: Components shown outside the dashed area are external to the device, and must be supplied by the user.**

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